CLAIMS

What is claimed is:

1	1. A method comprising:		
2	integrating an inductor on a spacer between upper and lower dies in stacked		
3	dies; and		
4	attaching conductors to electrically connect the inductor to one of the upper and		
5	lower dies.		
1	2. The method of claim 1 further comprising:		
2	filling adhesive between the spacer and the upper die and between the spacer		
3	and the lower die.		
	2 The weeth of of the in-1 wherein integrating commisses:		
1	3. The method of claim 1 wherein integrating comprises:		
2	integrating the inductor being a thin-film inductor.		
1	4. The method of claim 1 wherein integrating comprises:		
2	integrating the inductor having a thickness substantially less than thickness of		
3	the spacer.		
1	5. The method of claim 4 wherein integrating comprises:		
2	integrating the inductor having a multi-turn geometry.		
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1	6. The method of claim 1 wherein integrating comprises:		
2	integrating the inductor having an inductance of approximately between 1 nH to		
3	10 nH.		
1	7. The method of claim 1 wherein attaching the conductors comprises:		
า	attaching bumps to electrically connect the inductor to at least one of the upper		
2	and lower dies.		
3	and lower dies.		
1	8. The method of claim 1 further comprising:		
2	filling adhesive between the lower die to a package substrate.		

A spacer assembly comprising:

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2	a inductor integrated on a spacer between upper and lower dies in stacked dies;			
3	and			
4	conductors attached to the inductor to connect the inductor to at least one of the			
5	upper and lower dies.			
1	10. The spacer assembly of claim 9 further comprising:			
2	adhesive layers filled between the spacer and the upper die and between the			
3 spacer and the lower die.				
1	11. The spacer assembly of claim 9 wherein the inductor is a thin-film			
2	inductor.			
2	inductor.			
1	12. The spacer assembly of claim 9 wherein the inductor has a thickness			
2	substantially less than thickness of the spacer.			
1	13. The spacer assembly of claim 12 wherein the inductor has a multi-turn			
2	geometry.			
1	14. The spacer assembly of claim 9 wherein the inductor has an inductance			
2	of approximately between 1 nH to 10 nH.			
1	15. The spacer assembly of claim 9 wherein the conductors comprises:			
2	bumps attached to the inductor to electrically connect the inductor to at least			
3	one of the upper and lower dies.			
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1	16. The spacer assembly of claim 9 wherein the lower die is attached to a			
2	package substrate by an adhesive between the lower die and the package substrate.			
1	17. A die assembly comprising:			
2	a package substrate;			
3	a plurality of stacked dies on the package substrate and having at least an uppe			
4	die and a lower die; and			
5	at least a spacer assembly between the upper and lower dies, the spacer			
6	assembly comprising:			
7	a inductor integrated on a spacer between the upper and lower dies, and			

8	conductors attached to the inductor to electrically connect the inductor
9	to at least one of the upper and lower dies.
1	18. The die assembly of claim 17 wherein the spacer assembly further
2	comprises:
3	adhesive layers filled between the spacer and the upper die and between the
4	spacer and the lower die.
1	19. The die assembly of claim 17 wherein the inductor is a thin-film
2	inductor.
1	20. The die assembly of claim 17 wherein the inductor has a thickness
2	substantially less than thickness of the spacer.
1	21. The die assembly of claim 20 wherein the inductor has a multi-turn
2	geometry.
1	22. The die assembly of claim 17 wherein the inductor has an inductance of
2	approximately between 1 nH to 10 nH.
2	approximately between 1 in to 10 in .
1	23. The die assembly of claim 17 wherein the conductors comprises:
2	bumps attached to the inductor to electrically connect the inductor to at least
3	one of the upper and lower dies.
1	24. The die assembly of claim 17 wherein the lower die is attached to the
2	package substrate by an adhesive between the lower die and the package substrate.
3	25. A method comprising:
4	integrating a resistor on a spacer between upper and lower dies in stacked dies;
5	and
6	attaching conductors to electrically connect the resistor to one of the upper and
7	lower dies.
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1	26. The method of claim 25 further comprising:
2	filling adhesive between the spacer and the upper die and between the spacer
3	and the lower die

1		27.	The method of claim 25 wherein integrating comprises:	
2		integrating the resistor being a thin-film resistor.		
1		28.	The method of claim 25 wherein integrating comprises:	
2			ating the resistor having a thickness substantially less than thickness of the	
3	spacer.		, and the second of the second	
1		29.	The method of claim 28 wherein integrating comprises:	
2		integrating the resistor having a multi-turn geometry.		
1		30.	The method of claim 25 wherein integrating comprises:	
2		integra	ating the resistor having a resistance of approximately between 0.2 ohm to	
3	2 ohms.			
1		31.	The method of claim 25 wherein attaching the conductors comprises:	
2		attachi	ing bumps to electrically connect the resistor to at least one of the upper	
3	and low	ower dies.		
1		32.	The method of claim 25 further comprising:	
2		filling	adhesive between the lower die to a package substrate.	
1		33.	A spacer assembly comprising:	
2		a resis	tor integrated on a spacer between upper and lower dies in stacked dies;	
3	and			
4		condu	ctors attached to the resistor to connect the resistor to at least one of the	
5	upper a	upper and lower dies.		
1		34.	The spacer assembly of claim 33 further comprising:	
2		adhesi	ve layers filled between the spacer and the upper die and between the	
3	spacer a	and the	e lower die.	
1		35.	The spacer assembly of claim 33 wherein the resistor is a thin-film	
2	resistor			

1	36.	The spacer assembly of claim 33 wherein the resistor has a thickness	
2	substantially less than thickness of the spacer.		
1	37.	The spacer assembly of claim 36 wherein the resistor has a multi-turn	
2	geometry.		
1	38.	The spacer assembly of claim 33 wherein the resistor has a resistance of	
2		between 0.2 ohm to 2 ohms.	
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1	39.	The spacer assembly of claim 33 wherein the conductors comprises:	
2	bumps	s attached to the resistor to electrically connect the resistor to at least one	
3	of the upper a	nd lower dies.	
1	40.	The spacer assembly of claim 33 wherein the lower die is attached to a	
2	package subst	rate by an adhesive between the lower die and the package substrate.	
1	41.	A die assembly comprising:	
2	•	age substrate;	
3	•	ality of stacked dies on the package substrate and having at least an upper	
4	die and a lowe	er die; and	
5	at leas	t a spacer assembly between the upper and lower dies, the spacer	
6	assembly com	prising:	
7		a resistor integrated on a spacer between the upper and lower dies, and	
8		conductors attached to the resistor to electrically connect the resistor to	
9		at least one of the upper and lower dies.	
1	42.	The die assembly of claim 41 wherein the spacer assembly further	
2	comprises:		
3	adhesive layers filled between the spacer and the upper die and between the		
4	spacer and the	e lower die.	
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1	43.	The die assembly of claim 41 wherein the resistor is a thin-film resistor.	
1	44.	The die assembly of claim 41 wherein the resistor has a thickness	

substantially less than thickness of the spacer.

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1	45.	The die assembly of claim 44 wherein the resistor has a multi-turn	
2	geometry.		
1	46.	The die assembly of claim 41 wherein the resistor has a resistance of	
2	approximately b	petween 0.2 ohm to 2 ohms.	
1	47.	The die assembly of claim 41 wherein the conductors comprises:	
2	bumps a	ttached to the resistor to electrically connect the resistor to at least one	
3	of the upper and lower dies.		
1	48.	The die assembly of claim 41 wherein the lower die is attached to the	
2	package substra	te by an adhesive between the lower die and the package substrate.	